Quad. 2-input AND Gates

HITACHI

ADE-205-250 (Z) 1st Edition March 1999

Description

The HD74LV08A has four two-input AND gates in a 14-pin package.

Low-voltage and high-speed operation is suitable for the battery-powered products (e.g., notebook computers), and the low-power consumption extends the battery life.

Features

- $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V operation}$
- All inputs V_{IH} (Max.) = 5.5 V (@ V_{CC} = 0 V to 5.5 V)
- All outputs V_0 (Max.) = 5.5 V (@ V_{CC} = 0 V)
- Typical V_{OL} ground bounce < 0.8 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- Typical V_{OH} undershoot > 2.3 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- Output current $\pm 6 \text{ mA}$ (@V_{CC} = 3.0 V to 3.6 V), $\pm 12 \text{ mA}$ (@V_{CC} = 4.5 V to 5.5 V)

Function Table

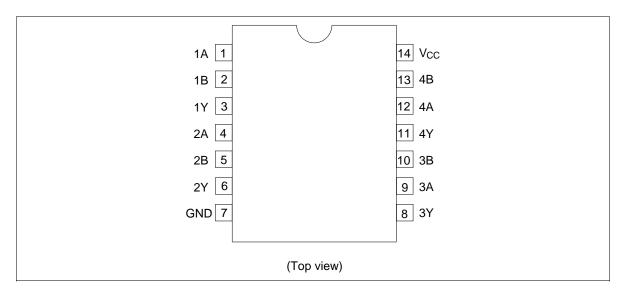
Inputs

A	В	Output Y
Н	Н	Н
L	X	L
X	L	L

Note: H: High level
L: Low level
X: Immaterial



Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	V _{cc}	-0.5 to 7.0	V	
Input voltage range*1	Vı	-0.5 to 7.0	V	
Output voltage range*1,2	Vo	-0.5 to V_{cc} + 0.5	V	Output: H or L
		-0.5 to 7.0	-	V _{cc} : OFF
Input clamp current	I _{IK}	-20	mA	V ₁ < 0
Output clamp current	I _{OK}	±50	mA	$V_{o} < 0 \text{ or } V_{o} > V_{cc}$
Continuous output current	Io	±25	mA	$V_{\rm O} = 0$ to $V_{\rm CC}$
Continuous current through V_{cc} or GND	I _{CC} or I _{GND}	±50	mA	
Maximum power dissipation at Ta = 25°C (in still air)*3	P _T	785	mW	SOP
		500	-	TSSOP
Storage temperature	Tsta	-65 to 150	°C	

Notes: The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

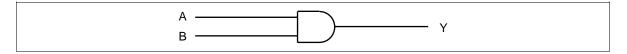
- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V _{cc}	2.0	5.5	V	
Input voltage range	V _I	0	5.5	V	
Output voltage range	Vo	0	V _{cc}	V	
Output current	I _{OH}	_	-50	μΑ	V _{CC} = 2.0 V
		_	-2	mA	$V_{cc} = 2.3 \text{ to } 2.7 \text{ V}$
		_	-6		$V_{cc} = 3.0 \text{ to } 3.6 \text{ V}$
		_	-12		$V_{cc} = 4.5 \text{ to } 5.5 \text{ V}$
	I _{OL}	_	50	μΑ	V _{CC} = 2.0 V
		_	2	mA	$V_{cc} = 2.3 \text{ to } 2.7 \text{ V}$
		_	6		$V_{cc} = 3.0 \text{ to } 3.6 \text{ V}$
		_	12		$V_{cc} = 4.5 \text{ to } 5.5 \text{ V}$
Input transition rise or fall rate	Δt/Δν	0	200	ns/V	$V_{cc} = 2.3 \text{ to } 2.7 \text{ V}$
		0	100		$V_{cc} = 3.0 \text{ to } 3.6 \text{ V}$
		0	20		$V_{cc} = 4.5 \text{ to } 5.5 \text{ V}$
Operating free-air temperature	Та	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

Logic Diagram



DC Electrical Characteristics

• $Ta = -40 \text{ to } 85^{\circ}C$

Item	Symbol	V _{cc} (V)*	Min	Тур	Max	Unit	Test Conditions
Input voltage	V _{IH}	2.0	1.5	_	_	V	
		2.3 to 2.7	$V_{CC} \times 0.7$	_	_	_	
		3.0 to 3.6	$V_{CC} \times 0.7$	_	_	_	
		4.5 to 5.5	$V_{CC} \times 0.7$	_	_	_	
	V _{IL}	2.0	_	_	0.5		
		2.3 to 2.7	_	_	$V_{CC} \times 0.3$	_	
		3.0 to 3.6	_	_	$V_{CC} \times 0.3$	_	
		4.5 to 5.5	_	_	$V_{CC} \times 0.3$		
Output voltage	V_{OH}	Min to Max	$V_{CC}-0.1$	_	_	V	$I_{OH} = -50 \mu A$
		2.3	2.0	_	_	_	I _{OH} = -2 mA
		3.0	2.48	_	_	_	I _{OH} = -6 mA
		4.5	3.8	_	_	_	I _{OH} = -12 mA
	V _{OL}	Min to Max	_	_	0.1		$I_{OL} = 50 \mu\text{A}$
		2.3	_	_	0.4	_	I _{OL} = 2 mA
		3.0	_	_	0.44	_	I _{OL} = 6 mA
		4.5	_	_	0.55	_	I _{OL} = 12 mA
Input current	I _{IN}	0 to 5.5	_	_	±1	μΑ	V _{IN} = 5.5 V or GND
Quiescent supply current	I _{cc}	5.5	_	_	20	μΑ	$V_{IN} = V_{CC}$ or GND, $I_{O} = 0$
Output leakage current	l _{OFF}	0	_	_	5	μΑ	V _O = 5.5 V
Input capacitance	C _{IN}	3.3	_	3.3	_	pF	$V_I = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

• $V_{CC} = 2.5 \pm 0.2 \text{ V}$

Ta = 25° C Ta = -40 to 85° C

Item	Symbol	Min	Тур	Max	Min	Max	Unit	Test Conditions	FROM (Input)	TO (Output)
Propa- gation delay time	t _{PLH} t _{PHL}	_	7.9	13.8	1.0	16.0	ns	C _L = 15 pF	A or B	Y
		_	10.5	17.3	1.0	20.0		C _L = 50 pF		

• $V_{CC} = 3.3 \pm 0.3 \text{ V}$

Ta = 25° C Ta = $-40 \text{ to } 85^{\circ}$ C

Item	Symbol	Min	Тур	Max	Min	Max	Unit	Test Conditions	FROM (Input)	TO (Output)
Propa- gation delay time	t _{PLH} t _{PHL}	_	5.6	8.8	1.0	10.5	ns	C _L = 15 pF	A or B	Y
	•	_	7.5	12.3	1.0	14.0		C _L = 50 pF		

• $V_{CC} = 5.0 \pm 0.5 \text{ V}$

		Ta =	25°C		Ta = -	-40 to 85°C				
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Test Conditions	FROM (Input)	TO (Output)
Propa- gation delay time	t _{PLH} t _{PHL}	_	4.1	5.9	1.0	7.0	ns	C _L = 15 pF	A or B	Y
		_	5.5	7.9	1.0	9.0	=	C _L = 50 pF		

Operating Characteristics

• $C_L = 50 \text{ pF}$

Ta = 25°C

Item	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	Test Conditions
Power dissipation capacitance	$C_{\mathtt{PD}}$	3.3	_	8.0	_	pF	f = 10 MHz
		5.0	_	10.0	_		

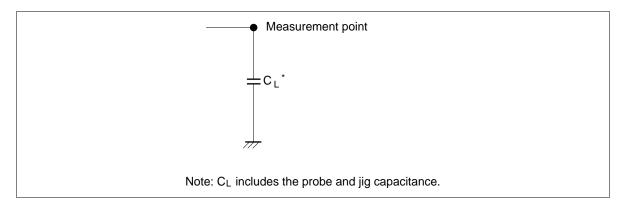
Noise Characteristics

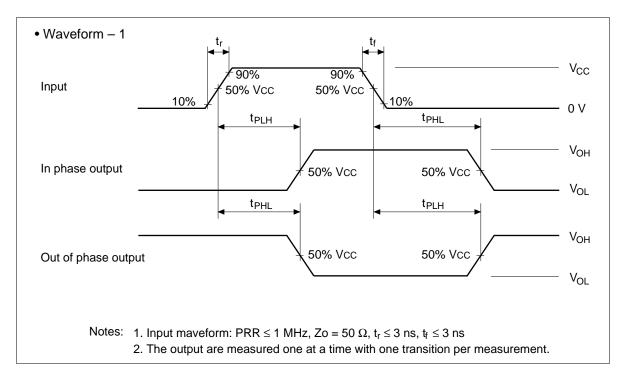
• $C_L = 50 \text{ pF}$

Ta = 25°C

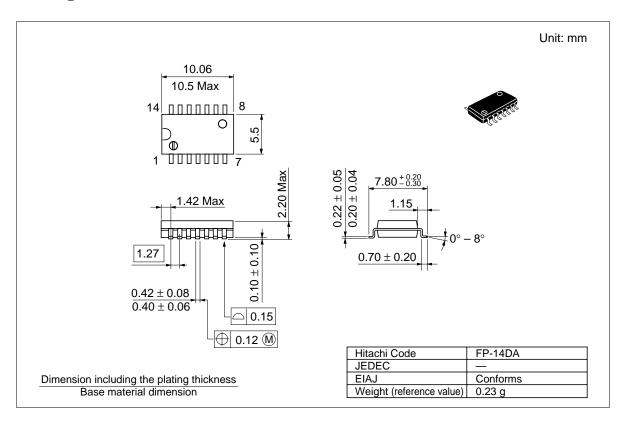
Item	Symbol	V_{cc} (V)	Min	Тур	Max	Unit	Test Conditions
Quiet output, maximum dynamic V _{OL}	$V_{OL(P)}$	3.3	_	0.2	0.8	V	
Quiet output, minimum dynamic V _{oL}	$V_{OL(V)}$	3.3	_	-0.1	-0.8		
Quiet output, minimum dynamic V _{OH}	$V_{OH(V)}$	3.3	_	3.1	_		
High-level dynamic input voltage	$V_{IH(D)}$	3.3	2.31	_	_	V	
Low-level dynamic inout voltage	V _{IL (D)}	3.3	_	_	0.99		

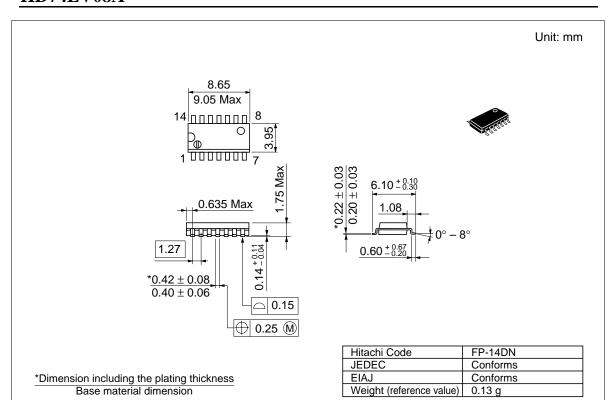
Test Circuit

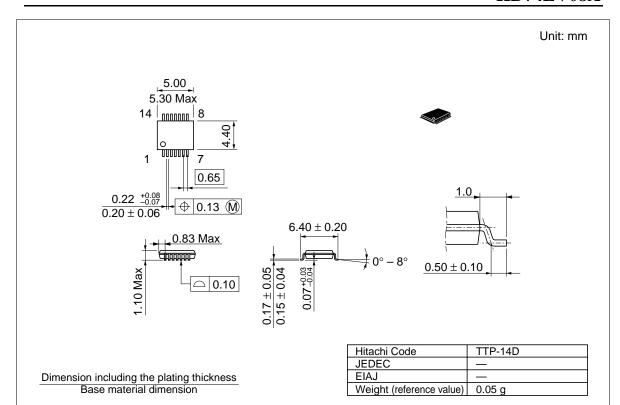




Package Dimensions







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